S14C202 Low Power +5V Powered EIA/TIA-232 Dual Driver/Receiver

💙 National Semiconductor

## **DS14C202** Low Power +5V Powered EIA/TIA-232 Dual **Driver/Receiver**

## **General Description**

The DS14C202 is a low power dual driver/receiver featuring an onboard DC to DC converter. This eliminates the need for ±12V power supplies and requires only a +5V power supply. Only four 0.1 µF capacitors are needed for the DC to DC converter. The drivers maintain greater than ±5V output signal levels at data rates in excess of 128 kbits/sec when loaded in accordance with the EIA/TIA-232-E specification.  $I_{\rm CC}$  is specified at 15 mA maximum, making the device ideal for battery and power conscious applications. The drivers' slew rate is set internally, eliminating the need for external slew rate capacitors. The device is designed to interface data terminal equipment (DTE) with data circuit-terminating equipment (DCE). The driver inputs and receiver outputs are TTL and CMOS compatible. DS14C202 driver outputs and receiver inputs meet EIA/TIA-232-E and ITU-T V.28 standards. This device is an enhanced version of the DS14C232

that requires smaller external capacitors (0.1 µF) and sup-

ports higher data rates of up to 128 kbit/sec.

## Features

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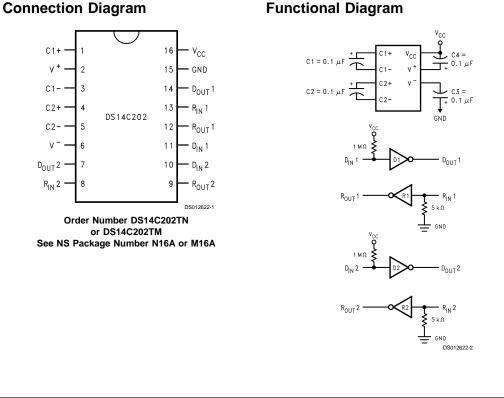
■ Uses only four small 0.1 µF capacitors for DC to DC converter

**ADVANCE INFORMATION** 

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- Operates over 128 kbit/sec
- Pin compatible with MAX202, MAX232A and others
- Single +5V power supply
- Low power
- DS14C202 meets EIA/TIA-232-E and ITU-T V.28 standards
- CMOS technology
- Package efficiency 2 drivers and 2 receivers
- Available in Plastic DIP and Narrow SOIC packages
- Extended temperature range: -40°C to +85°C
- ESD ≥ 6.0 kV HBM





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## Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

Supply Voltage (V <sub>CC</sub> )	-0.3V to 6V
Supply Voltage (V <sup>+</sup> )	(V <sub>CC</sub> – 0.3V) to +14V
Supply Voltage (V <sup>-</sup> )	+0.3V to -14V
Short Circuit Duration, DOUT	Continuous
Driver Input Voltage	–0.3V to (V <sub>CC</sub> + 0.3V)
Driver Output Voltage	$(V^+ + 0.3V)$ to $(V^ 0.3V)$
Receiver Input Voltage	±25V
Receiver Output Voltage	–0.3V to (V <sub>CC</sub> + 0.3V)
ESD Rating (HBM, 1.5 kΩ, 100 pF) Junction Temperature	≥ 6.0 kV +150°C

Maximum Package Power Dissipation @ 25°C (Note 6)				
N Package	TBD			
M Package	TBD			
Storage Temperature Range	-65°C to +150°C			
Lead Temperature (Soldering, 4 sec.)	+260°C			

# Recommended Operating Conditions

	Min	Max	Units
Supply Voltage, (V <sub>CC</sub> )	4.5	5.5	V
Operating Free Air Temp. (T <sub>A</sub> )			
DS14C202T	-40	+85	°C

## Electrical Characteristics (Notes 2, 5)

Over recommended operating conditions, unless otherwise specified.

Symbol	Parameter	Conditions		Min	Тур	Max	Units
DEVICE	CHARACTERISTICS					1	
V <sup>+</sup>	Positive Power Supply	$R_1 = 3 k\Omega$ , C1–C4 = 0.1 µF, $D_{IN} = 0.8V$			9.0		V
V-	Negative Power Supply	$R_{L} = 3 \text{ k}\Omega, \text{ C1-C4} = 0.1 \mu\text{F}, D_{\text{IN}} = 2.0^{\circ}$	V		-8.5		V
I <sub>cc</sub>	V <sub>CC</sub> Supply Current	No Load				15	mA
DRIVER	CHARACTERISTICS						
V <sub>IH</sub>	High Level Input Voltage			2.0		V <sub>cc</sub>	V
V <sub>IL</sub>	Low Level Input Voltage			GND		0.8	V
I <sub>IH</sub>	High Level Input Current	$V_{IN} \ge 2.0V$		-30		+30	μA
I <sub>IL</sub>	Low Level Input Current	$V_{IN} \le 0.8V$		-30		+30	μA
V <sub>OH</sub>	High Level Output Voltage	$R_{L} = 3 k\Omega$		5.0	8.0		V
V <sub>OL</sub>	Low Level Output Voltage	$R_{L} = 3 k\Omega$			-7.0	-5.0	V
los+	Output High Short Circuit Current	$V_{OUT} = 0V, V_{IN} = 0.8V$ (	Note 3)	-5.0	-15	-30	mA
I <sub>os</sub> <sup>-</sup>	Output Low Short Circuit Current	$V_{OUT} = 0V, V_{IN} = 2.0V$		5.0	11	30	mA
Ro	Output Resistance	$-2V \le V_{OUT} \le +2V, V_{CC} = 0V = GND c$	or Open	300			Ω
RECEIVE	R CHARACTERISTICS						
V <sub>TH</sub>	Input High Threshold Voltage				1.7	2.4	V
V <sub>TL</sub>	Input Low Threshold Voltage			0.8	1.5		V
V <sub>HY</sub>	Hysteresis			0.2	0.4	1.0	V
R <sub>IN</sub>	Input Resistance	$-15V \le V_{IN} \le +15V$		3.0	4.7	7.0	kΩ
I <sub>IN</sub>	Input Current	V <sub>IN</sub> = +15V		+2.14	+3.5	+5.0	mA
		$V_{IN} = +3V$		+0.43	+0.6	+1.0	mA
		$V_{IN} = -3V$		-0.43	-0.6	-1.0	mA
		$V_{IN} = -15V$		-2.14	-3.5	-5.0	mA
V <sub>он</sub>	High Level Output Voltage	$V_{IN} = -3V, I_{OH} = -3.2 \text{ mA}$		3.5	4.5		V
		V <sub>IN</sub> = -3V, I <sub>OH</sub> = -20 μA		4.0	4.9		V
V <sub>OL</sub>	Low Level Output Voltage	$V_{IN} = +3V, I_{OL} = +3.2 \text{ mA}$			0.15	0.4	V

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Symbol	Parameter	Conditions		Min	Тур	Max
DRIVER	CHARACTERISTICS					
t <sub>PLH</sub>	Propagation Delay Low to High	$R_{L} = 3 k\Omega$			1.0	4.(
t <sub>PHL</sub>	Propagation Delay High to Low	$C_{L} = 50 \text{ pF}$			1.0	4.
t <sub>sk</sub>	Skew  t <sub>PLH</sub> – t <sub>PHL</sub>	(Figure 1)			0.1	1.
SR1	Output Slew Rate	$R_1 = 3 k\Omega$ to 7 k $\Omega$ , $C_1 = 50 pF$	(Note 7)	4.0	10	30
SR2	Output Slew Rate	$R_1 = 3 k\Omega$ to 7 k $\Omega$ , $C_1 = 2500 pF$	,	4.0	10	30
RECEIV					1	
t <sub>PLH</sub>	Propagation Delay Low to High	Input Pulse Width > 10 µs				2.
t <sub>PHL</sub>	Propagation Delay High to Low	$C_{L} = 50  \text{pF}$				2.
t <sub>sk</sub>	Skew  t <sub>PLH</sub> - t <sub>PHL</sub>	(Figure 2)				30
tr	Output Rise Time	-		<u> </u>		1
t <sub>f</sub>	Output Fall Time	-				1
DATA R	•					
(MAXON	Maximum Data Rate	$R_{L}$ = 3 k $\Omega$ to 7 k $\Omega$ , $C_{L}$ = 50 pF to 1	000 pF (Note 8)	128	TBD	
	1	s beyond which the safety of the device cannot be			1	that the
for test p Note 5: Note 6: Note 7: Note 8:	urposes: $t_r = t_f = 10$ ns (10% to 90%), $V_{IH} =$ All typicals are given for $V_{CC} = 5.0V$ , +25°C. Ratings apply to ambient temperature at +25 Slew rate is defined as $\Delta V/\Delta t$ , measured bet	5°C. Above this temperature derate: N Package TE ween $\pm$ 3V level. or a waveform that is ½ rise, ½ fall, ½ logic level (	D and M Package TBD. driver ±5V and receiver			
	▼ ♥ GN DS0	Driver Load Circuit and Switching Wa	0V 0V - SR- veform (Note 4)	- 		DS0126

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## **Pin Descriptions**

### V<sub>cc</sub> (Pin 16)

Power supply pin for the device,  $+5V (\pm 10\%)$ .

#### V⁺ (Pin 2)

Positive supply for EIA/TIA-232-E drivers. Recommended external capacitor: C4 = 0.1  $\mu F$  ( $\geq$  6.3V). Capacitor value should not be less than 0.1  $\mu F$ . This supply is not intended to be loaded externally. (Note 9)

## V<sup>-</sup> (Pin 6)

Negative supply for EIA/TIA-232-E drivers. Recommended external capacitor: C3 = 0.1  $\mu$ F ( $\geq$  16V). Capacitor value should not be less than 0.1  $\mu$ F. This supply is not intended to be loaded externally. (Note 9)

#### C1+, C1- (Pins 1, 3)

External capacitor connection pins. Recommended capacitor: C1 = 0.1  $\mu F$  ( $\geq$  6.3V). Capacitor value should not be less than 0.1  $\mu F.$  (Note 9)

#### C2+, C2- (Pins 4, 5)

www.DataSheet4U.com External capacitor connection pins. Recommended capacitor:  $C2 = 0.1 \ \mu F$  ( $\geq 16V$ ). Capacitor value should not be less than 0.1  $\mu F$ . (Note 9)

## **Typical Application Information**

## D<sub>IN</sub>1, D<sub>IN</sub>2 (Pins 11, 10)

Driver input pins are TTL/CMOS compatible. Inputs of unused drivers may be left open, an internal active pull-up resistor (500 k $\Omega$  minimum, typically 1 M $\Omega$ ) pulls input HIGH. Output will be LOW for input pins.

### $D_{\text{OUT}}\mathbf{1},\,D_{\text{OUT}}\mathbf{2}$ (Pins 14, 7)

Driver output pins conform to EIA/TIA-232-E levels.

#### R<sub>IN</sub>1, R<sub>IN</sub>2 (Pins 13, 8)

Receiver input pins accept EIA/TIA-232-E input voltages (±25V). Receivers feature guaranteed hysteresis of 200 mV. Unused receiver input pins may be left open. Internal input resistor (5 k $\Omega$ ) pulls input LOW, providing a fail-safe HIGH output.

#### R<sub>OUT</sub>1, R<sub>OUT</sub>2 (Pins 12, 9)

Receiver output pins are TTL/CMOS compatible. Receiver output HIGH voltage is specified for both CMOS and TTL load conditions.

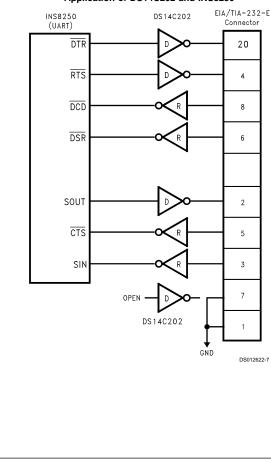
## GND (Pin 15)

#### Ground Pin.

Note 9: All capacitor values have tolerances of less than  $\pm 20\%$ .

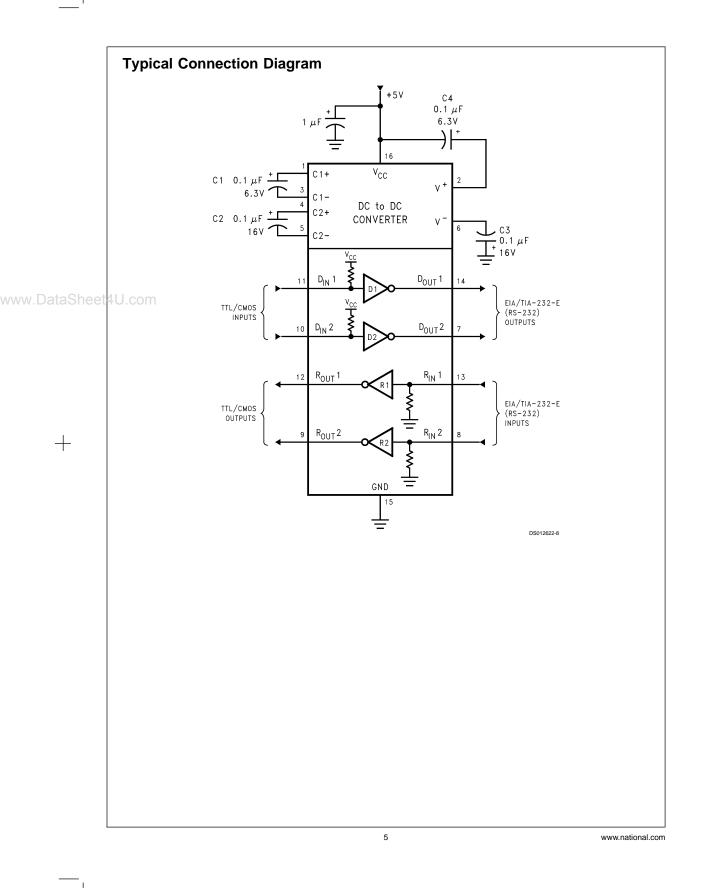
#### Application of DS14C202 and INS8250

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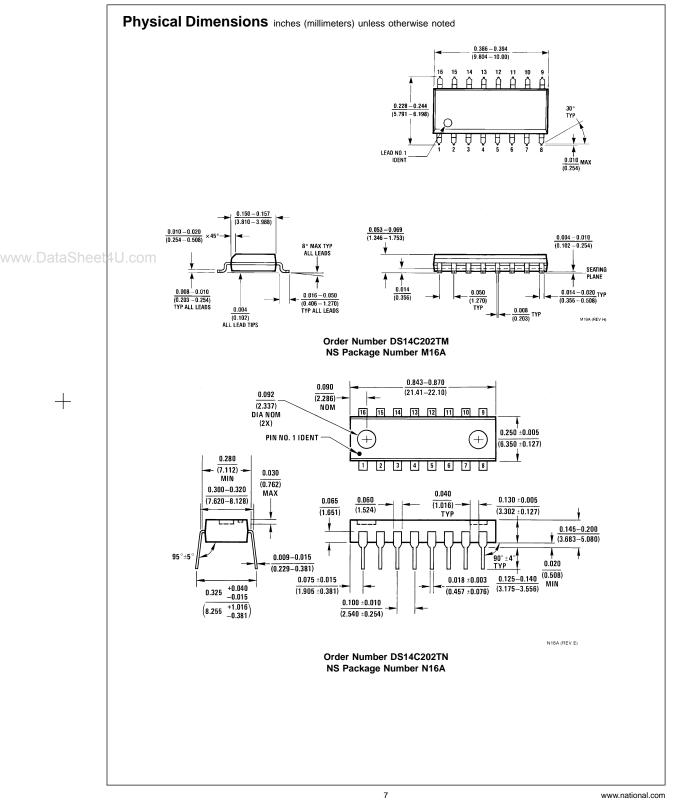
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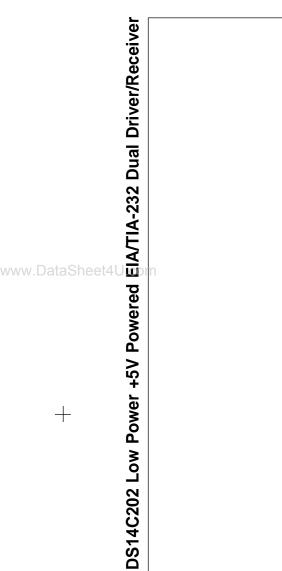
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